1. General description

NPN high power bipolar transistor in a power DPAK, TO-252 (SOT428C) Surface-Mounted Device (SMD) plastic package.

PNP complement: MJD32CA

2. Features and benefits

- · High thermal power dissipation capability
- · High energy efficiency due to less heat generation
- Electrically similar to popular MJD31 series
- Low collector emitter saturation voltage
- Fast switching speeds
- AEC-Q101 qualified

3. Applications

- Power management
- Load switch
- Linear mode voltage regulator
- Constant current drive backlighting application
- Motor drive
- · Relay replacement

4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------|---------------------------|---|-----|-----|-----|------|
| V _{CEO} | collector-emitter voltage | open base | - | - | 100 | V |
| I _C | collector current | | - | - | 3 | Α |
| I _{CM} | peak collector current | single pulse; t _p ≤ 1 ms | - | - | 5 | Α |
| h _{FE} | DC current gain | V _{CE} = 4 V; I _C = 1 A; T _{amb} = 25 °C | 25 | - | - | |
| | | V _{CE} = 4 V; I _C = 3 A; T _{amb} = 25 °C | 10 | - | 50 | |



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5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|---------------------------------------|--------------------|----------------|
| 1 | В | base | mb | E |
| 2 | С | collector | | в -{* |
| 3 | Е | emitter | | C; mb |
| mb | С | mounting base; connected to collector | DPAK (SOT428C) | aaa-029889 |

6. Ordering information

Table 3. Ordering information

| Type number | | | |
|-------------|------|---|---------|
| | Name | Description | Version |
| MJD31CA | DPAK | Plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped) | SOT428C |

7. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| MJD31CA | MJD31CA |

8. Limiting values

Table 5. Limiting values

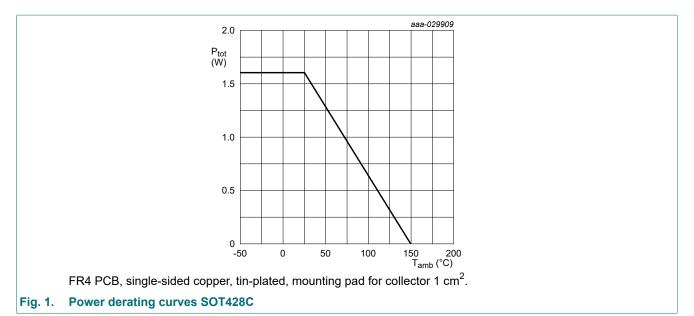
In accordance with the Absolute Maximum Rating System (IEC601134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|---------------------------|-------------------------------------|-----|-----|-----|------|
| V _{CEO} | collector-emitter voltage | open base | | - | 100 | V |
| V _{EBO} | emitter-base voltage | open collector | | - | 6 | V |
| I _C | collector current | | | - | 3 | А |
| I _{CM} | peak collector current | single pulse; t _p ≤ 1 ms | | - | 5 | А |
| P _{tot} | total power dissipation | T _{mb} ≤ 25 °C | [1] | - | 15 | W |
| | | T _{amb} ≤ 25 °C | [2] | - | 1.6 | W |
| Tj | junction temperature | | | - | 150 | °C |
| T _{amb} | ambient temperature | | | -55 | 150 | °C |
| T _{stg} | storage temperature | | | -65 | 150 | °C |

[1] Total power dissipation junction to mounting base.

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated mounting pad for collector 1 cm².

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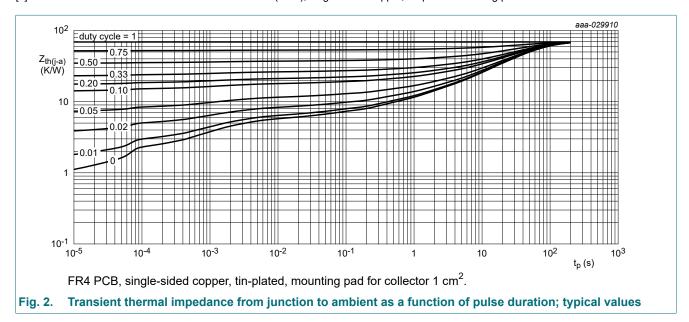


9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|-----------------------|---|-------------|-----|-----|-----|-----|------|
| R _{th(j-mb)} | thermal resistance from junction to mounting base | in free air | | - | - | 9 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient | | [1] | - | - | 79 | K/W |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated mounting pad for collector 1 cm².



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10. Characteristics

Table 7. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--------------------|--------------------------------------|---|-----|-----|-----|------|
| I _{CES} | collector-emitter cut-off | V _{CE} = 80 V; V _{BE} = 0 V; T _{amb} = 25 °C | - | - | 1 | μΑ |
| | current | V _{CE} = 64 V; V _{BE} = 0 V; T _j = 150 °C | - | - | 50 | μΑ |
| I _{EBO} | emitter-base cut-off current | $V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$ | - | - | 1 | μA |
| h _{FE} | DC current gain | V _{CE} = 4 V; I _C = 1 A; T _{amb} = 25 °C | 25 | - | - | |
| | | V _{CE} = 4 V; I _C = 3 A; T _{amb} = 25 °C | 10 | - | 50 | |
| V _{CEsat} | collector-emitter saturation voltage | $I_C = 3 \text{ A}; I_B = 375 \text{ mA}; T_{amb} = 25 \text{ °C}$ | - | - | 1.2 | V |
| V _{BE} | base-emitter voltage | V _{CE} = 4 V; I _C = 3 A; T _{amb} = 25 °C | - | - | 1.8 | V |
| h _{fe} | small-signal current gain | V_{CE} = 10 V; I_{C} = 500 mA; f = 1 Hz; T_{amb} = 25 °C | 20 | - | - | |
| f _T | transition frequency | V_{CE} = 10 V; I_{C} = 500 mA; f = 1 MHz; T_{amb} = 25 °C | 3 | - | - | MHz |

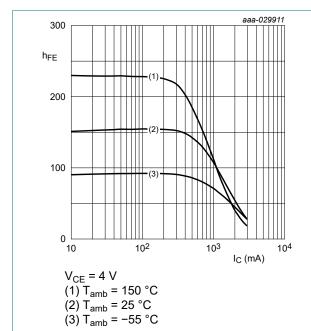


Fig. 3. DC current gain as a function of collector current; typical values

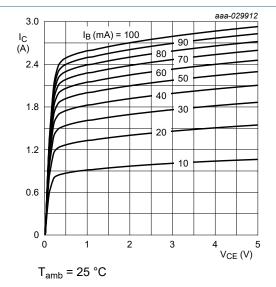
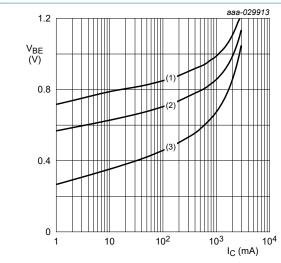


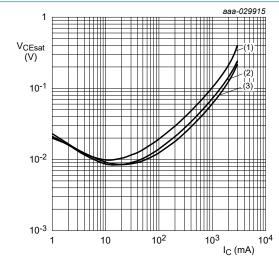
Fig. 4. Collector current as a function of collectoremitter voltage; typical values

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V_{CE} = 4 V (1) T_{amb} = -55 °C (2) T_{amb} = 25 °C (3) T_{amb} = 150 °C

Fig. 5. Base-emitter voltage as a function of collector current; typical values



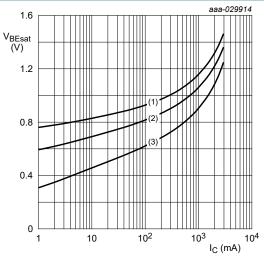
 $I_{\rm C}/I_{\rm B} = 10$

(1) T_{amb} = 150 °C

(2) $T_{amb} = 25 \, ^{\circ}C$

(3) $T_{amb} = -55 \, ^{\circ}C$

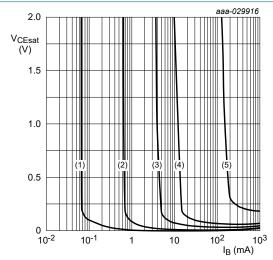
Fig. 7. Collector-emitter saturation voltage as a function of collector current; typical values



 $I_{C}/I_{B} = 10$ (1) $T_{amb} = -55 \,^{\circ}C$ (2) $T_{amb} = 25 \,^{\circ}C$

(3) T_{amb} = 150 °C

Fig. 6. Base-emitter saturation voltage as a function of collector current; typical values



(1) $I_C = 10 \text{ mA}$

(2) $I_C = 100 \text{ mA}$

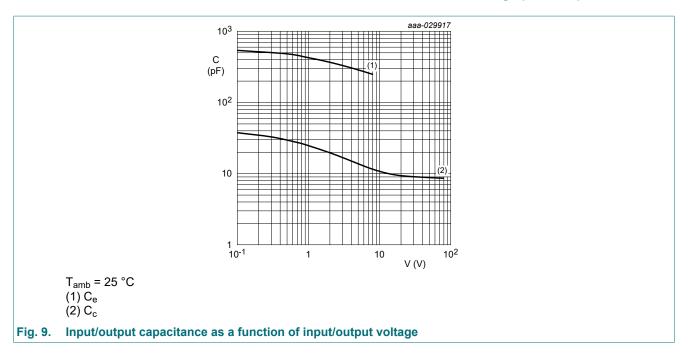
(3) $I_C = 500 \text{ mA}$

 $(4) I_C = 1000 \text{ mA}$

 $(5) I_C = 3000 \text{ mA}$

Fig. 8. Collector-emitter saturation region as a function of base current; typical values

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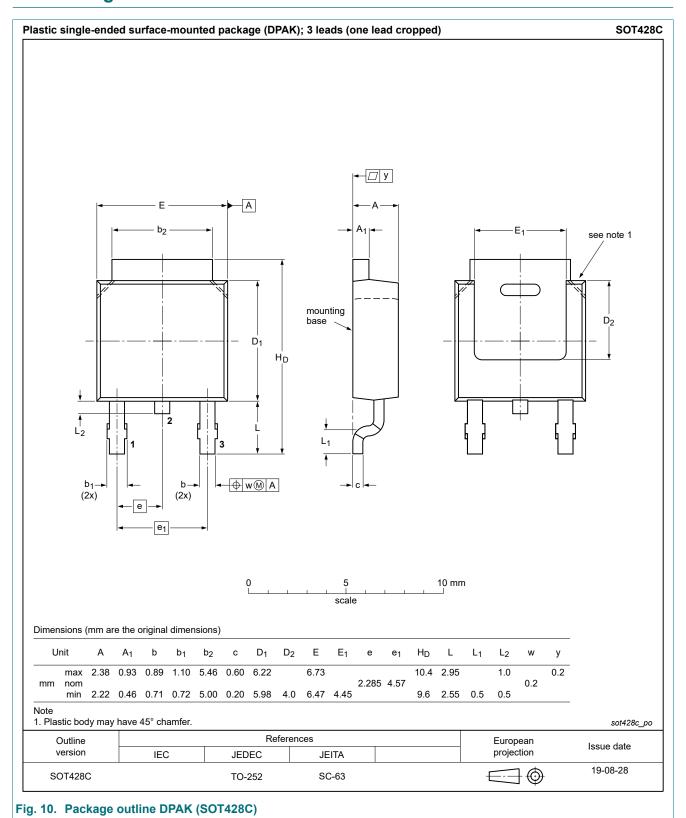
11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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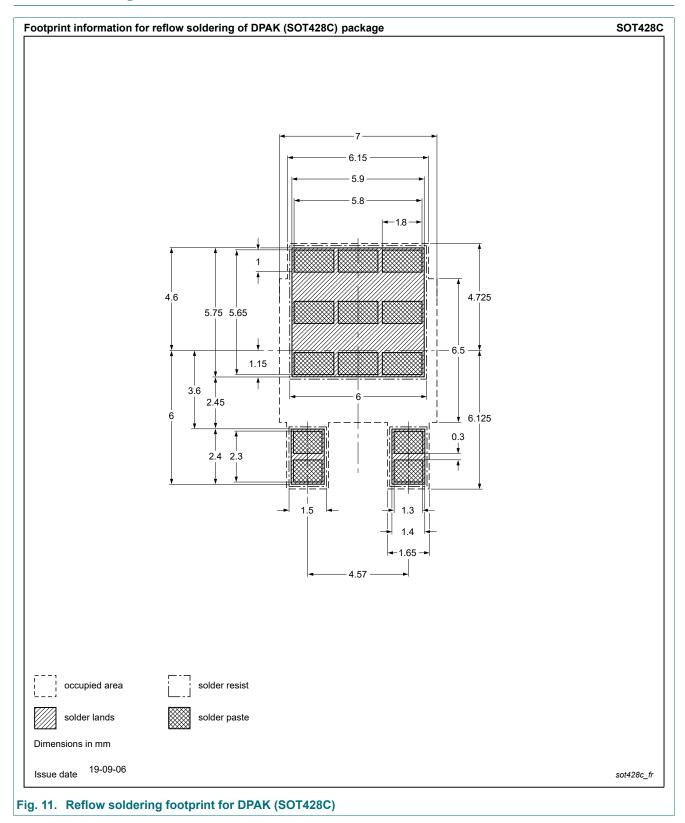
12. Package outline



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13. Soldering



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14. Revision history

Table 8. Revision history

| , | | | | | | | |
|----------------|---|------------------------|---------------|-------------|--|--|--|
| Data sheet ID | Release date | Data sheet status | Change notice | Supersedes | | | |
| MJD31CA v.4 | 20190912 | Product data sheet | - | MJD31CA v.3 | | | |
| Modifications: | Package outline ada | pted to SOT428C | | | | | |
| MJD31CA v.3 | 20190802 | Product data sheet | - | MJD31CA v.2 | | | |
| MJD31CA v.2 | 20190729 | Product data sheet | - | MJD31CA v.1 | | | |
| MJD31CA v.1 | 20190523 | Preliminary data sheet | - | - | | | |

15. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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